

EE 464 Homework 3

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1 Derivation of Input to Output TF

To derive TF, first I will find small signal circuit equivalent. Forward converter can be treated as a buck converter with $V_{in} = n \cdot V_{in}$ where n is transformer ratio.

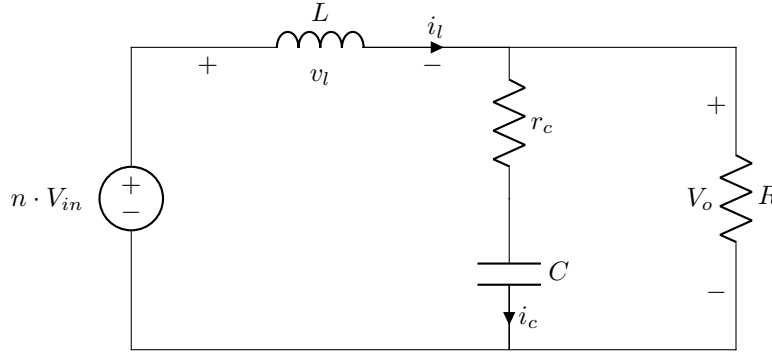


Figure 1: Simplified Forward Converter when switch is on

KVL at the outer path,

$$-nV_{in} + L \frac{di}{dt} + i_o R = 0 \quad (1)$$

Since,

$$i_o = i_l - i_c \quad (2)$$

$$L \frac{di}{dt} = nV_{in} - Ri_l + Ri_c \quad (3)$$

Find i_c by KVL on inductor and capacitor

$$-nV_{in} + L \frac{di}{dt} + i_c r_c + V_c = 0 \quad (4)$$

$$i_c = \frac{nV_{in} - L \frac{di}{dt} - V_c}{r_c} \quad (5)$$

Insert i_c into equation 3,

$$\hat{i}_l = \frac{di}{dt} = \frac{nV_{in}}{L} - \frac{r_c R}{(r_c + R)L} \frac{R}{(r_c + R)L} V_c \quad (6)$$

We know that $R \gg r_c$ so we can simplify equation as,

$$\hat{i}_l = \frac{nV_{in}}{L} - \frac{r_c}{L} i_l - \frac{1}{L} v_c \quad (7)$$

Start derive V_c by KCL at output node,

$$i_c = i_l - \frac{V_o}{R} \quad (8)$$

Since,

$$v_o = v_c + r_c i_c \quad (9)$$

$$i_c = \frac{R}{R + r_c} i_l - \frac{1}{R + r_c} v_l \quad (10)$$

Since,

$$\hat{v}_c = \frac{i_c}{C} \quad (11)$$

$$\hat{v}_c = \frac{R}{C(R + r_c)} i_l - \frac{1}{C(R + r_c)} v_l \quad (12)$$

We know that $R \gg r_c$ so we can simplify equation as,

$$\hat{V}_c = \frac{1}{C} i_l - \frac{1}{RC} v_l \quad (13)$$

According to state space equations,

$$\begin{bmatrix} \hat{i}_l \\ \hat{v}_c \end{bmatrix} = \begin{bmatrix} -\frac{r_c}{L} & -\frac{1}{C} \\ \frac{1}{C} & -\frac{1}{RC} \end{bmatrix} \begin{bmatrix} i_l \\ v_c \end{bmatrix} + \begin{bmatrix} \frac{n}{L} \\ 0 \end{bmatrix} V_{in} \quad (14)$$

For switch off position A matrix hasn't changed. But B matrix multiplied with duty ratio so,

$$\begin{bmatrix} \hat{i}_l \\ \hat{v}_c \end{bmatrix} = \begin{bmatrix} -\frac{r_c}{L} & -\frac{1}{C} \\ \frac{1}{C} & -\frac{1}{RC} \end{bmatrix} \begin{bmatrix} i_l \\ v_c \end{bmatrix} + \begin{bmatrix} \frac{dn}{L} \\ 0 \end{bmatrix} V_{in} \quad (15)$$

Find v_o as state space variables,

$$v_o = v_c + r_c i_c \quad (16)$$

Since,

$$i_c = i_l - \frac{v_o}{R} \quad (17)$$

$$v_o = v_c + r_c i_l - \frac{v_o r_c}{R} \quad (18)$$

$$v_o = \frac{r_c R}{r_c + R} i_l + \frac{R}{(r_c + R)} v_c \quad (19)$$

Since $r_c \ll 1$,

$$v_o = r_c i_l + v_c \quad (20)$$

$$C = \begin{bmatrix} r_c \\ 1 \end{bmatrix} \quad (21)$$

$$\frac{v_o(s)}{d(s)} = C^T [SI - A]^{-1} B V_{in} \quad (22)$$

After a lengthy evaluation control to output TF is,

$$G_{vd} = \left. \frac{\tilde{v}_o}{\tilde{d}} \right|_{\tilde{v}_i=0} = \frac{nV_{in}}{LC} \left[\frac{sr_c C + 1}{s^2 + s(\frac{r_c}{L} + \frac{1}{RC}) + \frac{1}{LC}} \right] \quad (23)$$

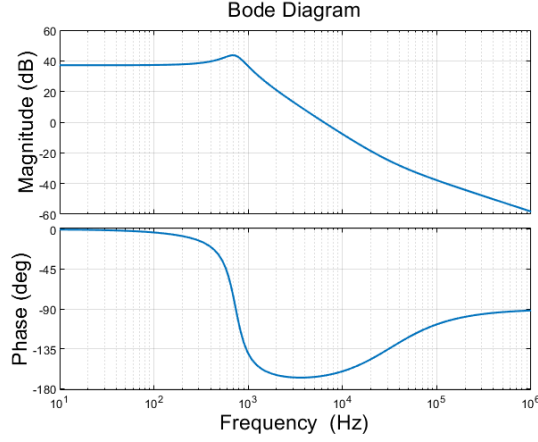


Figure 2: Bode plot of control to output TF

According to **erickson** Crossover Frequency is defined as the frequency where the magnitude of loop gain is unity. Limit for f_c is pole frequency since we want to operate unity gain at f_c . For power application switching frequency selected as one in ten or five. For this application I select as,

$$f_c = \frac{f_{sw}}{5} = 20kHz \quad (24)$$

Since $f_{ESR} = 32kHz$ and $f_{LC} = 734Hz$,

$$f_{LC} < f_c < f_{ESR} < f_{sw}/2 \quad (25)$$

Compensator Type	Relative location of the crossover and power-stage frequencies	Typical Output Capacitor
Type II (PI)	$F_{LC} < F_{ESR} < F_0 < F_s/2$	Electrolytic, POS-Cap, SP-Cap
Type III-A (PID)	$F_{LC} < F_0 < F_{ESR} < F_s/2$	POS-Cap, SP-Cap
Type III-B (PID)	$F_{LC} < F_0 < F_s/2 < F_{ESR}$	Ceramic

Figure 3: Compensator Selection table

According to table 3 I select Type 3-A compensator for this application. Type 3 compensator supplies phase boost for this converter to operate stable region.

2 Compensator Parameters

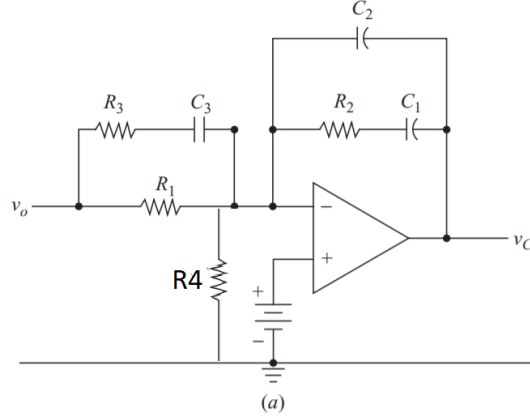


Figure 4: Type 3 Compensator

This compensator is referred from **erickson** book except one extension. R_4 added to adjust input voltage range. When $f_c = 20kHz$, from bode plot phase angle is -146 and gain is -20 db. $V_{ref} = 3V$, which corresponds -9.5 db.

$$|G(j\omega_o)| = 29.5dB = 29.5Gain \quad (26)$$

$$\theta_{comp} = \theta_{phase-margin} - \theta_{converter} = 45 - (-146) = 191 \quad (27)$$

$$K = \tan\left(\frac{191 + 90}{2}\right)^2 = 7.75 \quad (28)$$

$$\begin{aligned} R_2 &= \frac{|G(j\omega_{co})|R_1}{\sqrt{K}} \\ C_1 &= \frac{\sqrt{K}}{\omega_{co}R_2} = \frac{\sqrt{K}}{2\pi f_{co}R_2} \\ C_2 &= \frac{1}{\omega_{co}R_2\sqrt{K}} = \frac{1}{2\pi f_{co}R_2\sqrt{K}} \\ C_3 &= \frac{\sqrt{K}}{\omega_{co}R_1} = \frac{\sqrt{K}}{2\pi f_{co}R_1} \\ R_3 &= \frac{1}{\omega_{co}\sqrt{K}C_3} = \frac{1}{2\pi f_{co}\sqrt{K}C_3} \end{aligned}$$

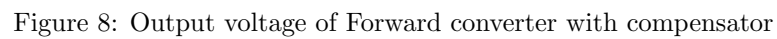
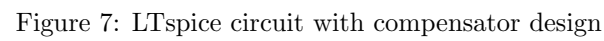
Figure 5: Type 3 Compensator equations

To start lets choose $R_1 = 1k\Omega$, Afterwards by using formulas at figure 5, other parameters found as,

$$R_2 = 10.77k\Omega \quad , \quad C_1 = 2nF \quad , \quad C_2 = 0.26nF \quad , \quad C_3 = 22nF \quad , \quad R_3 = 130\Omega \quad (29)$$

It is suitable to measure output voltage with $\frac{v_o}{3}$,

$$v_{ref} = \frac{v_o}{3} \frac{R_4}{R_4 + R_1} \implies R_4 = \frac{v_{ref}R_1}{\frac{v_o}{3} - v_{ref}} = 1.5k\Omega \quad (30)$$



3 Current Mode Controller

We select LT3758 current mode controller for this application. According to datasheet output voltage formula determined by feedback loop,

$$V_o = 1.6 \cdot \left(1 + \frac{R2}{R1}\right) \quad (31)$$

To have 15V resistor selected as,

$$R1 = 10k\Omega \quad , \quad R2 = 83.75k\Omega \quad (32)$$

Sense pin is directly fed from to source of mosfet. R_{sense} used at the source of mosfet. According to datasheet

$$R_{sense} = \frac{80mV}{I_{l-peak}} = 0.01\Omega \quad (33)$$

Since operating frequency is 100kHz, according to datasheet 140k Ω fasten to RT pin. Also error amplifier used in this controller. At the datasheet they suggest to use typical application parametes at the datasheet.

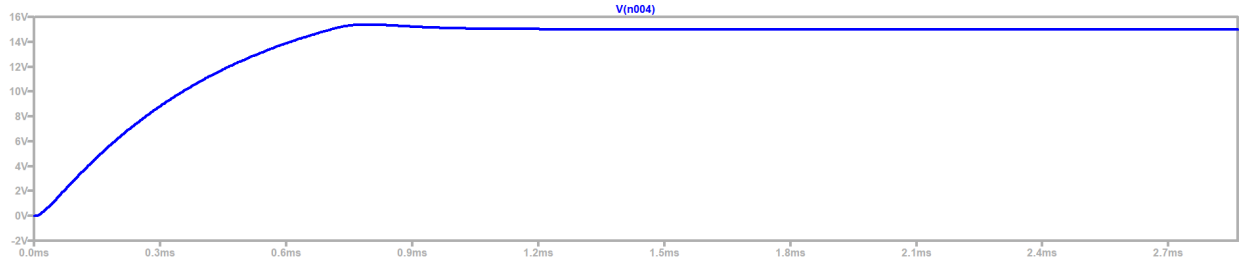


Figure 9: Output Voltage with current mode controller

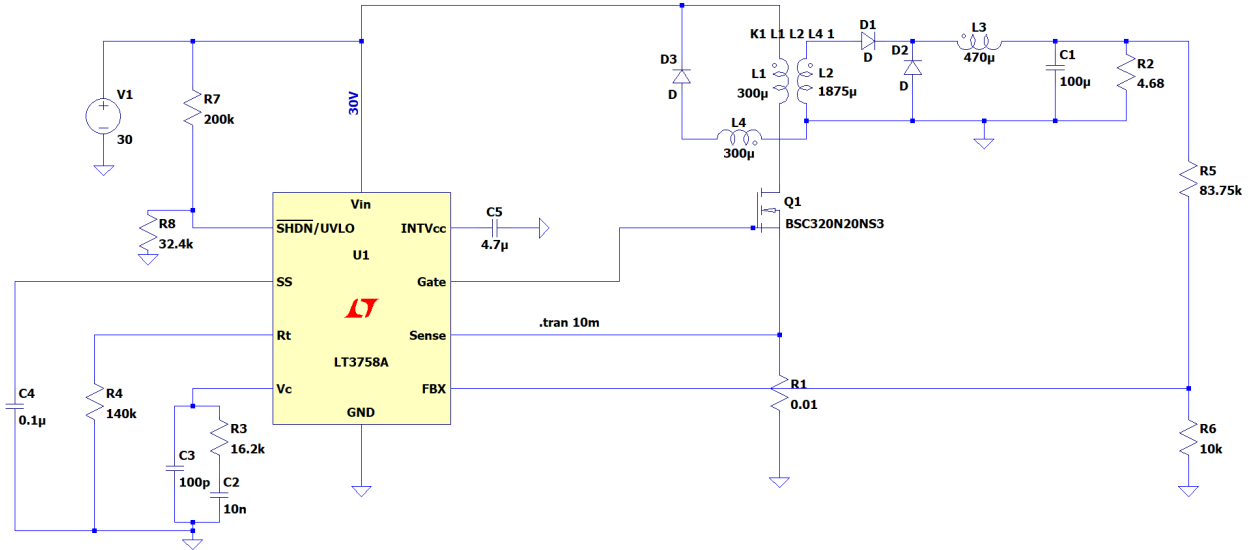


Figure 10: Circuit with current mode controller

Current mode controller is advantageous when compare with voltage control compensator. It is important that settling time of current mode controller is 5 times better than voltage control. Also steady state ripple decreases.

Thermal analysis checked by calculations before. In this section we will prove that simulation tools also gives close result with calculations.

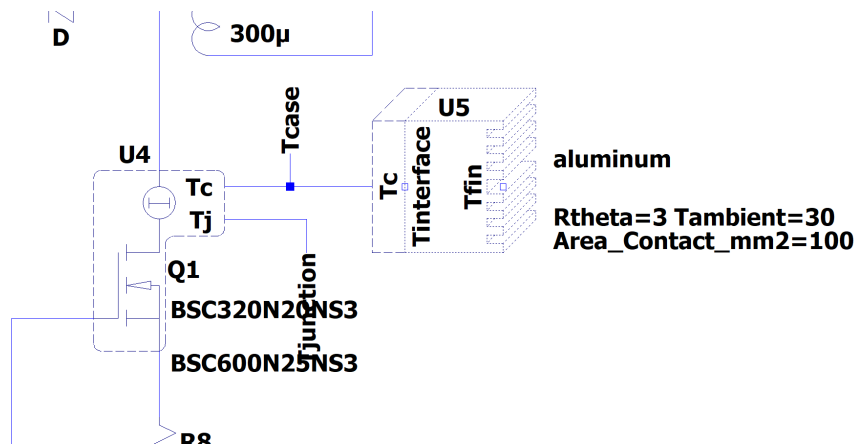


Figure 11: Thermal analysis simulation design

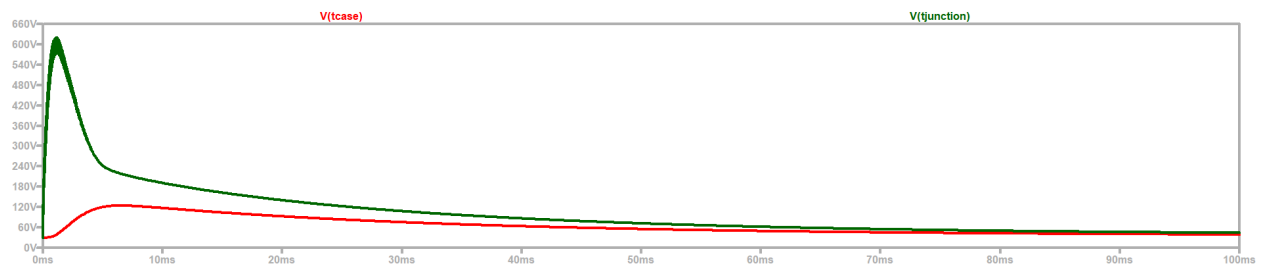


Figure 12: Junction and case temperatures when voltage compensator used

Figure 12 shows that FET temperature is saturated at 40 Celcius if ambient is 30 celcius.